Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-260-2918

	nclosure Material:
0	Glass
(	Overall Length:
C	0.300 inches
٦	Ferminal Length:
1	.500 inches
(	Overall Diameter:
C	0.107 inches
	loint Electronic Device Engineering Council/jedec/case Outline Designation:
0	Do-7
N	Nounting Method:
٦	Ferminal
F	Features Provided:
ŀ	Hermetically sealed case
ę	Semiconductor Material:
S	Silicon
١	/oltage Rating In Volts Per Characteristic:
6	5.2 regulator voltage
١	/oltage Tolerance In Percent:
-	5.0/+5.0
(	Current Rating Per Characteristic:
1	.00 milliamperes source cutoff current horsepower metric
F	Power Rating Per Characteristic:
2	00.0 milliwatts small-signal input power, common-collector absolute
ſ	Iaximum Operating Tempurature Per Measurement Point:
	75.0 degrees celsius ambient air
	Ferminal Type And Quantity:
	2 uninsulated wire lead
	Shelf Life:
	√a
ι	Jnit Of Measure:
-	-
	Demilitarization:
	lo
	iig:
1	A110a0